



MNx Ultra-Compact Microchip Series



KEY FEATURES

- Ultra-compact package
- 1535 nm, 1064 nm and 532 nm
- Ultra-short pulses down to 650 ps
- Multi-kW peak power
- Excellent beam quality TEM00, M²<1.1
- · Efficient, air-cooled

The MNx series are our most compact microchip lasers and cover the mid-IR to visible part of the spectrum. They integrate the pump diode, the micro-cavity and even the second harmonic generation crystal in a package less than 7 cm long. The 1064nm engine produces sub-nanosecond pulses with several kW peak power, achieving over 50% second harmonic generation efficiency at 532 nm. The 153 5nm micro-laser displays similar performances with a few nanoseconds pulse duration.

APPLICATIONS

- Super-continuum generation
- Marking
- Raman spectrometry
- Rangin



TECHNICAL SPECIFICATIONS

	MNE-06E-100	MNP-08E-100	MNG-03E-100
Wavelength	1535nm	1064nm	532nm
Repetition Rate	>2kHz	>5kHz	>5kHz
Constant Pulse width range (FWHM) ⁽¹⁾	<3.5ns	<1ns	<0.75ns
Output power ⁽²⁾	>12mW	>40mW	>15mW
Output energy	>6µJ	>8µJ	>3µJ
Peak Power	>1.5kW	>8kW	>4kW
Short term (1min) power stability ⁽³⁾	<±1%	<±1%	<±1%
Long term (6 hrs) power stability ⁽³⁾	<±5%	<±3%	<±3%
Beam profile Full angle divergence	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00
Horizontal@1/e² Vertical@1/e²	23±3.4 mrad 23±3.6 mrad	12±2 mrad 14±2 mrad	10±2 mrad 9±2 mrad
M ²⁽⁴⁾	<1.3	<1.3	<1.3
Beam ellipticity ⁽⁵⁾	<1.2	<1.3	<1.3
Polarization	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB
Package dimensions	100x22x32mm	68x41x29mm	68x41x29mm
Package weight	250g	250g	250g
Options (table p3)	-	M	-

NOTES

 ⁽¹⁾ Measured with 1Ghz photodiode and 1GHz/10GS/s oscilloscope.
 (2) Measurement performed with an OPHIR thermal power sensor (OPHIR 3A-FS-SH).
 (3) For temperature variation < ± 3°C and < 3°C/hour, stability is measured with calorimeter - detector band [DC, 2Hz]
 (4) Mean average value M = √(XY), X and Y being respectively the major and minor axis of the ellipse
 (5) Beam ellipticity is calculated as the ratio of the main axis far field divergence

FOR YOUR APPLICATION, FIND YOUR PULSED LASER SOLUTION



COMPLEMENTARY INFORMATION & OPTIONS

Environment Parameters				
Operating Temperature Range	0-50°C			
Maximum Laser Head Baseplate Temperature	<50°C			
Maximum Power Consumption	<40W			
Laser Head Thermal Dissipation	<10W			
Storage Temperature	0-50°C			
Shock of 11ms according to IEC 68-2-27, non operating	25g			
Vibration 5Hz to 500Hz sinusoïdal according to IEC 68-2-6	2g			

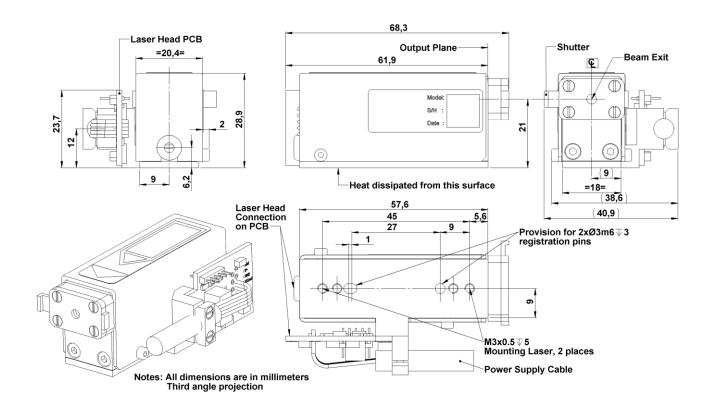
Certification					
Laser classification according to IEC 60825-1:2007	3R for MNE-06E 3B MNP-08E and MNG-03E				
CDRH	Yes, if used with a -DR1 controller				
ROHs	Yes				

Options	
Multimode fibering (M)	Contact factory for availability

Available Controller Types					
Model	Туре	Input Power	CDRH		
MLC-03A-DR1	Desktop	100-240 V AC	Yes		
MLC-03A-MR1	Module	12 V DC	No		
MLC-03A-BR1	Board	12 V DC	No		



CDRH LASER HEAD MECHANICAL DRAWINGS: MNP-08E-100, MNG-03E-100







CDRH LASER HEAD MECHANICAL DRAWINGS: MNE-06E-100

